1058036

MAKE-A-RECORD OF

STEVENS & SHOWALTER, L.L.P.

Ittorneys at Law

7019 CORPORATE WAY DAYTON, OHIO 45459-4238

PATENTS, TRADEMARKS, COPYRIGHTS & RELATED MATTERS

BRADLEY T. LIGIBEL

ICHARD C STEVENS

ROBERT L. SHOWALTER*

MICHAEL D. FOLKERTS

OF COUNSEL

TODD E. STOCKWELL*
CHRISTOPHER T. SMEDLEYA
WESLEY L. STRICKLAND+

* ALSO ADMITTED IN KENTUCKY

Δ ADMITTED ONLY IN KENTUCKY

+ ADMITTED ONLY IN KENTUCKY, DC AND VIRGINIA

November 17, 2010

TELEPHONE (937) 438-6848 FACSIMILE (937) 438-2124 EMAIL: SSLLP@SPEAKEASY.NET

Commissioner of Patents P.O. Box 1450 Alexandria, VA 22313-1450

Re:

Patent No.

: US 7,790,569 B2

Issued

September 7, 2010

Title

PRODUCTION OF SEMICONDUCTOR

SUBSTRATES WITH BURIED LAYERS BY JOINING (BONDING) SEMICONDUCTOR

WAFERS

Docket No.

LEO 003 PA

Sir:

When the printed patent was compared with the attorneys' file copy, the following errors were noted:

Col. 2, line 59, "this diameter is also to taken in the" should read --this diameter is also to be taken in the--;

Col. 2, line 66, "which result in an transfer of structures" should read --which result in a transfer of structures-;

Col. 4, line 33, "wafer structure of to bonded wafers" should read --wafer structure of bonded wafers--.

It is thought that these errors are not of material importance, and accordingly no certificate of correction is being requested. It is merely asked that this correspondence be placed of record in the file as calling attention to these errors.

Respectfully submitted

Richard C. Stevens Reg. No. 28,046